

To our customers,

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April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

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Not recommended  
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# HAF1002(L), HAF1002(S)

Silicon P Channel MOS FET Series  
Power Switching

REJ03G1133-0200  
(Previous: ADE-208-586)  
Rev.2.00  
Sep 07, 2005

## Description

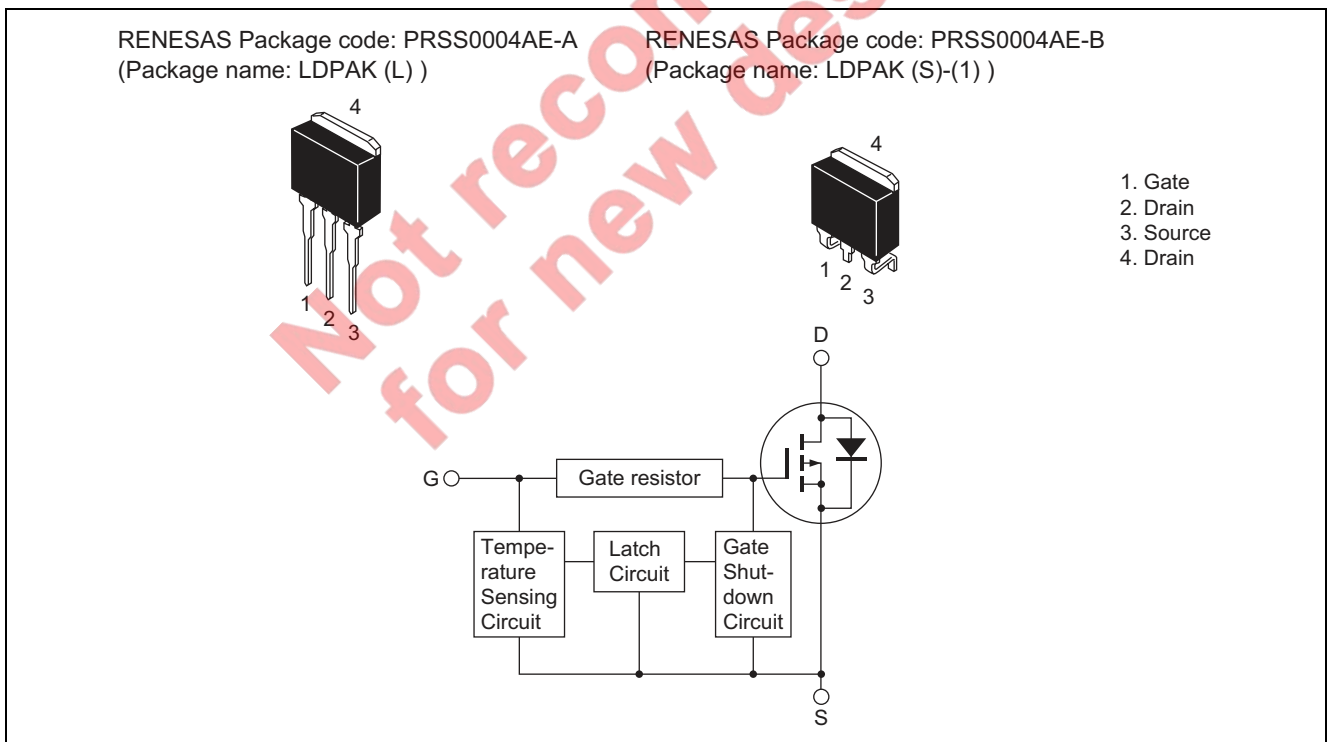
This FET has the over temperature shut-down capability sensing to the junction temperature.

This FET has the built-in over temperature shut-down circuit in the gate area. And this circuit operation to shut-down the gate voltage in case of high junction temperature like applying over power consumption, over current etc.

## Features

- Logic level operation (-4 to -6 V Gate drive)
- High endurance capability against to the short circuit
- Built-in the over temperature shut-down circuit
- Latch type shut-down operation (Need 0 voltage recovery)

## Outline



## Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Value	Unit
Drain to source voltage	V <sub>DS</sub>	-60	V
Gate to source voltage	V <sub>GSS</sub>	-16	V
	V <sub>GSS</sub>	3	V
Drain current	I <sub>D</sub>	-15	A
Drain peak current	I <sub>D (pulse)</sub> <sup>Note 1</sup>	-30	A
Body-drain diode reverse drain current	I <sub>DR</sub>	-15	A
Channel dissipation	P <sub>ch</sub> <sup>Note 2</sup>	50	W
Channel temperature	T <sub>ch</sub>	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C

Notes: 1. PW ≤ 10 ∞s, duty cycle ≤ 1%

2. Value at Tc = 25°C

## Typical Operation Characteristics

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Input voltage	V <sub>IH</sub>	-3.5	—	—	V	
	V <sub>IL</sub>	—	—	-1.2	V	
Input current (Gate non shut down)	I <sub>IH1</sub>	—	—	-100	∞A	Vi = -8 V, V <sub>DS</sub> = 0
	I <sub>IH2</sub>	—	—	-50	∞A	Vi = -3.5 V, V <sub>DS</sub> = 0
	I <sub>IL</sub>	—	—	-1	∞A	Vi = -1.2 V, V <sub>DS</sub> = 0
Input current (Gate shut down)	I <sub>IH (sd) 1</sub>	—	-0.8	—	mA	Vi = -8 V, V <sub>DS</sub> = 0
	I <sub>IH (sd) 2</sub>	—	-0.35	—	mA	Vi = -3.5 V, V <sub>DS</sub> = 0
Shut down temperature	T <sub>sd</sub>	—	175	—	°C	Channel temperature
Gate operation voltage	V <sub>OP</sub>	-3.5	—	-13	V	

Not recommended for new designs

## Electrical Characteristics

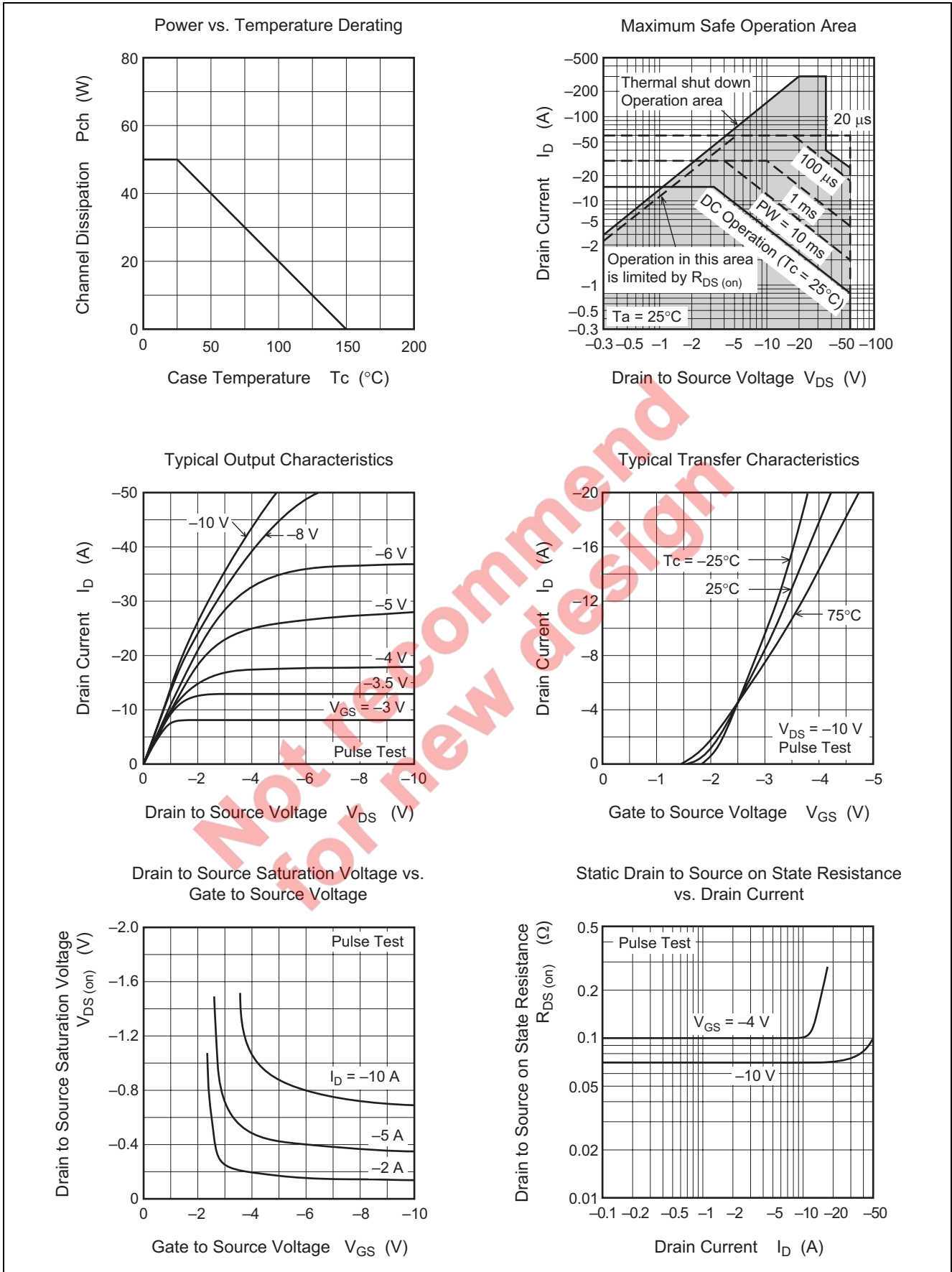
(Ta = 25°C)

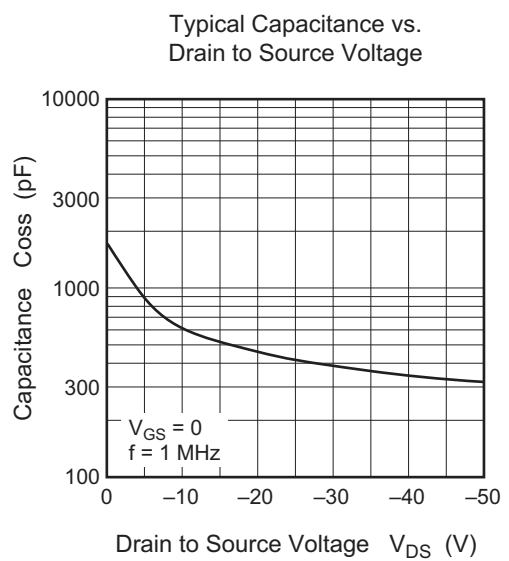
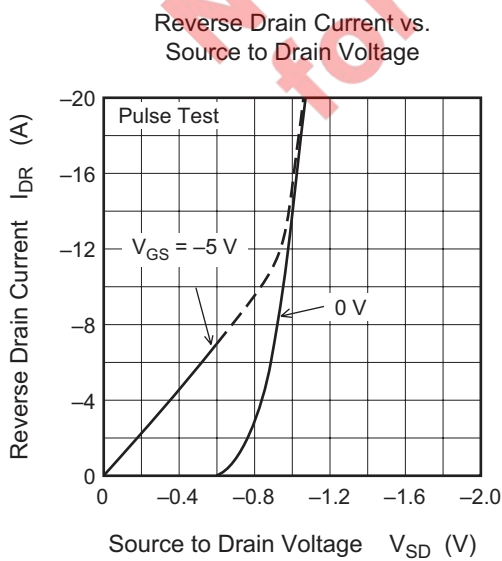
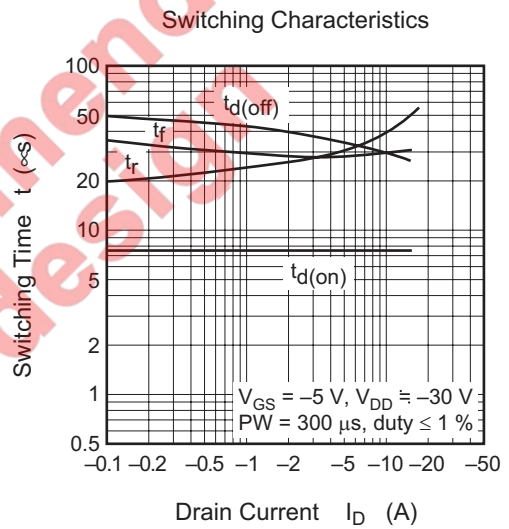
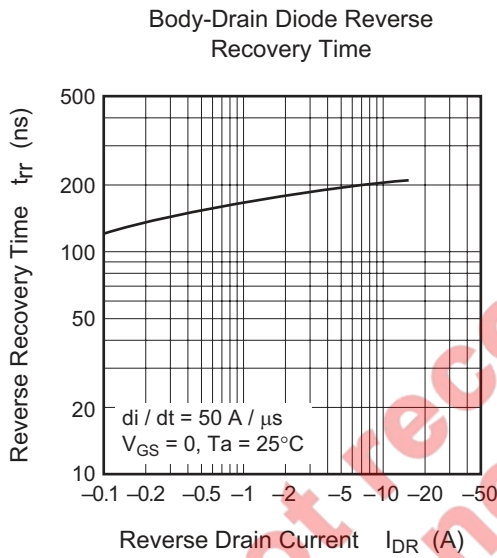
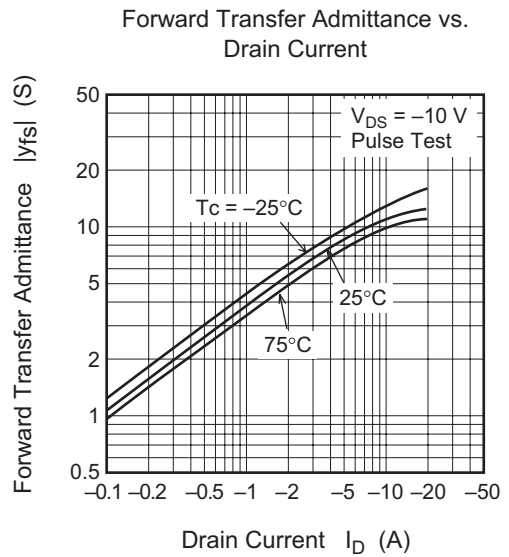
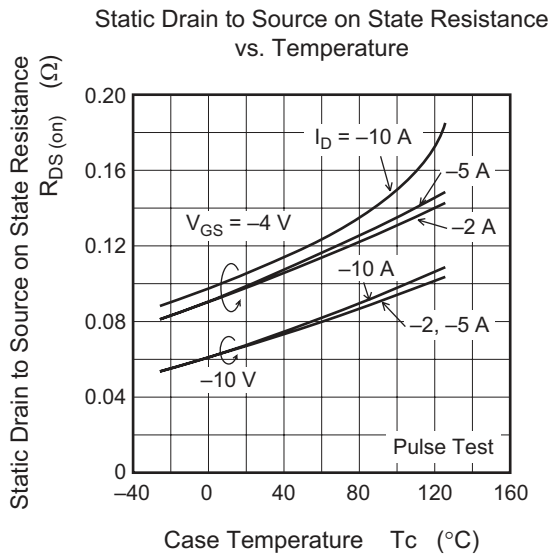
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain current	$I_{D1}$	-7	—	—	A	$V_{GS} = -3.5 \text{ V}, V_{DS} = -2 \text{ V}$
	$I_{D2}$	—	—	-10	mA	$V_{GS} = -1.2 \text{ V}, V_{DS} = -2 \text{ V}$
Drain to source breakdown voltage	$V_{(BR)DSS}$	-60	—	—	V	$I_D = -10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	-16	—	—	V	$I_G = -100 \text{ } \mu\text{A}, V_{DS} = 0$
	$V_{(BR)GSS}$	3	—	—	V	$I_G = 100 \text{ } \mu\text{A}, V_{DS} = 0$
Gate to source leak current	$I_{GSS1}$	—	—	-100	$\mu\text{A}$	$V_{GS} = -8 \text{ V}, V_{DS} = 0$
	$I_{GSS2}$	—	—	-50	$\mu\text{A}$	$V_{GS} = -3.5 \text{ V}, V_{DS} = 0$
	$I_{GSS3}$	—	—	-1	$\mu\text{A}$	$V_{GS} = -1.2 \text{ V}, V_{DS} = 0$
	$I_{GSS4}$	—	—	100	$\mu\text{A}$	$V_{GS} = 2.4 \text{ V}, V_{DS} = 0$
Input current (shut down)	$I_{GS(op)1}$	—	-0.8	—	mA	$V_{GS} = -8 \text{ V}, V_{DS} = 0$
	$I_{GS(op)2}$	—	-0.35	—	mA	$V_{GS} = -3.5 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	$I_{DSS}$	—	—	-250	$\mu\text{A}$	$V_{DS} = -50 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	-1.1	—	-2.25	V	$I_D = -1 \text{ mA}, V_{DS} = -10 \text{ V}$
Static drain to source on state resistance	$R_{DS(on)}$	—	100	130	m $\Omega$	$I_D = -7.5 \text{ A}, V_{GS} = -4 \text{ V}$ <sup>Note 3</sup>
	$R_{DS(on)}$	—	70	90	m $\Omega$	$I_D = -7.5 \text{ A}, V_{GS} = -10 \text{ V}$ <sup>Note 3</sup>
Forward transfer admittance	$ y_{fs} $	5	10	—	S	$I_D = -7.5 \text{ A}, V_{DS} = -10 \text{ V}$ <sup>Note 3</sup>
Output capacitance	$C_{oss}$	—	610	—	pF	$V_{DS} = -10 \text{ V}, V_{GS} = 0$ $f = 1 \text{ MHz}$
Turn-on delay time	$t_{d(on)}$	—	7.5	—	$\infty$ s	$I_D = -7.5 \text{ A}$
Rise time	$t_r$	—	36	—	$\infty$ s	$V_{GS} = -5 \text{ V}$
Turn-off delay time	$t_{d(off)}$	—	32	—	$\infty$ s	$R_L = 4 \text{ } \Omega$
Fall time	$t_f$	—	29	—	$\infty$ s	
Body-drain diode forward voltage	$V_{DF}$	—	-1.0	—	V	$I_F = -15 \text{ A}, V_{GS} = 0$
Body-drain diode reverse recovery time	$t_{rr}$	—	200	—	ns	$I_F = -15 \text{ A}, V_{GS} = 0$ $di_F/dt = 50 \text{ A}/\infty\text{s}$
Over load shut down operation time <sup>Note4</sup>	$t_{os1}$	—	3.7	—	ms	$V_{GS} = -5 \text{ V}, V_{DD} = -12 \text{ V}$
	$t_{os2}$	—	1	—	ms	$V_{GS} = -5 \text{ V}, V_{DD} = -24 \text{ V}$

Notes: 3. Pulse test

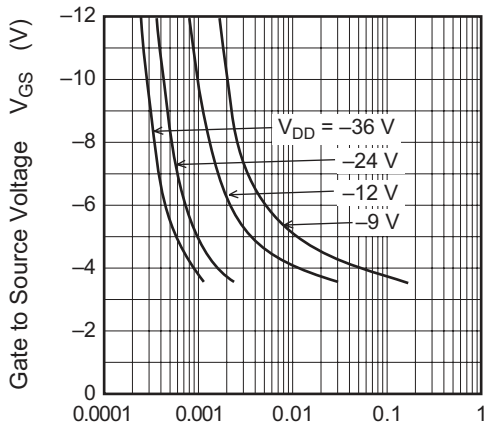
4. Include the time shift based on increasing of channel temperature when operate under over load condition.

Main Characteristics



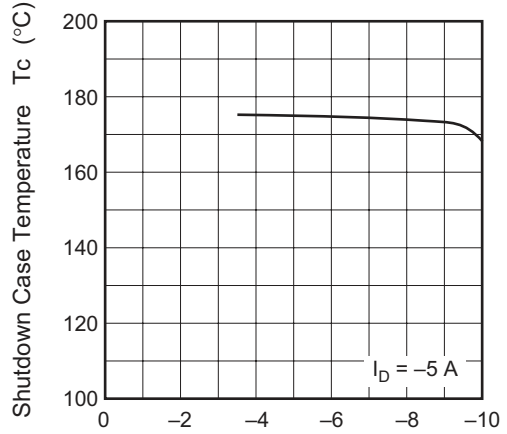


Gate to Source Voltage vs. Shutdown Time of Load-Short Test



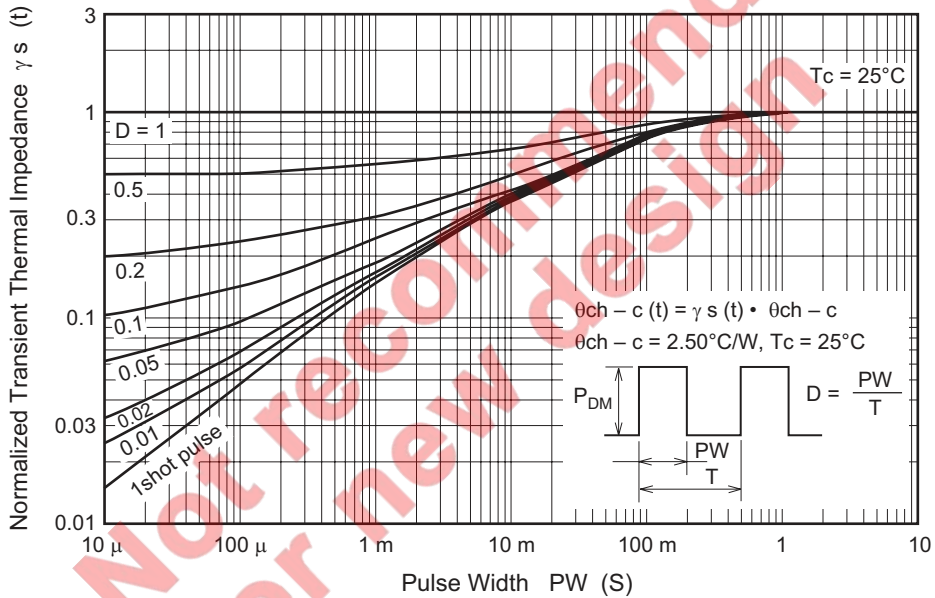
Shutdown Time of Load-Short Test PW (S)

Shutdown Case Temperature vs. Gate to Source Voltage

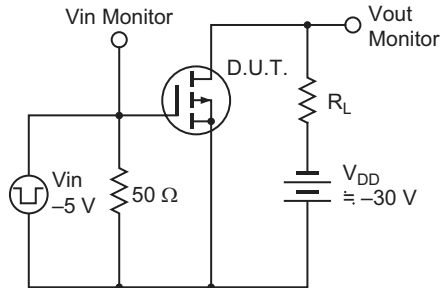


Gate to Source Voltage  $V_{GS}$  (V)

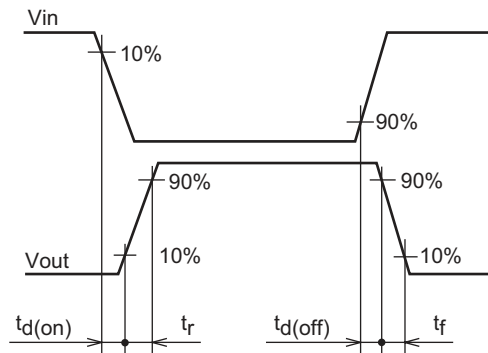
Normalized Transient Thermal Impedance vs. Pulse Width



Switching Time Test Circuit

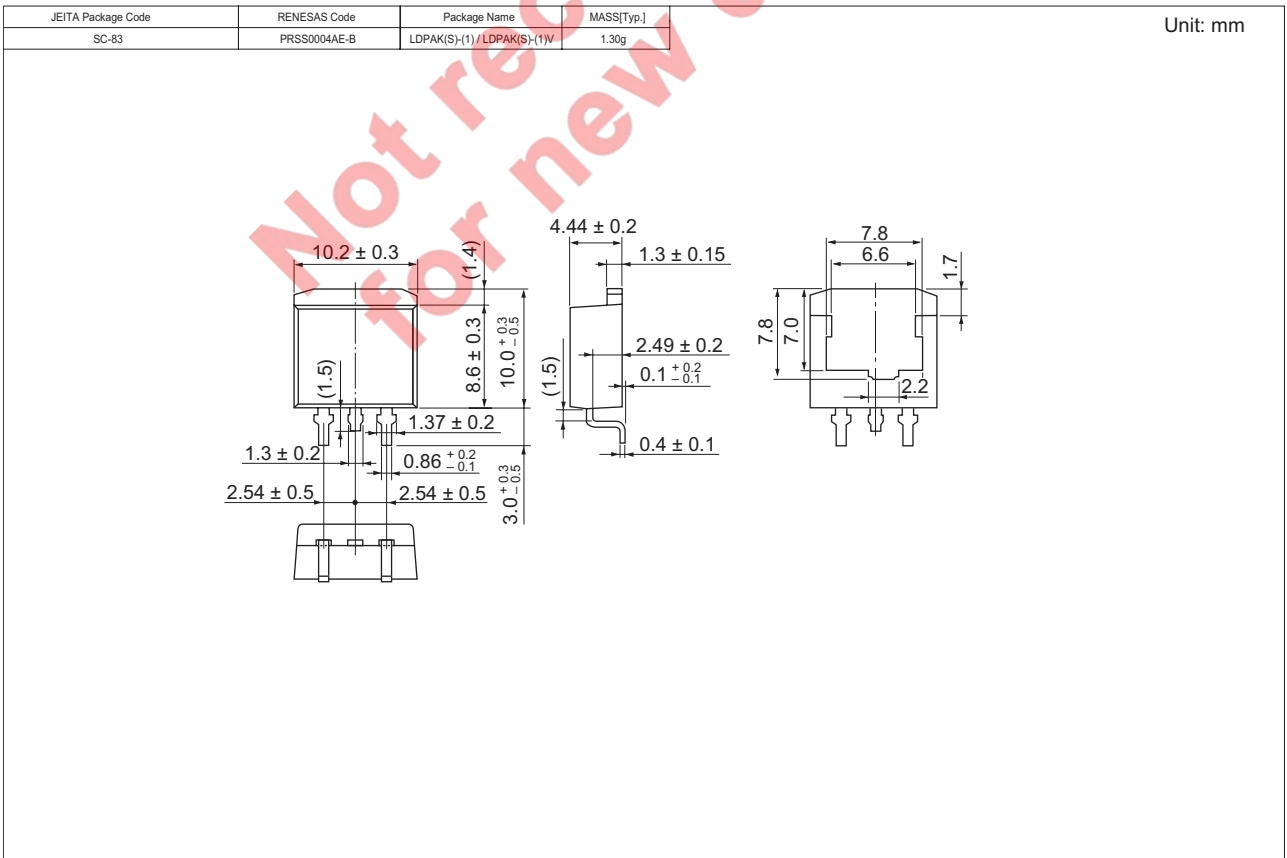
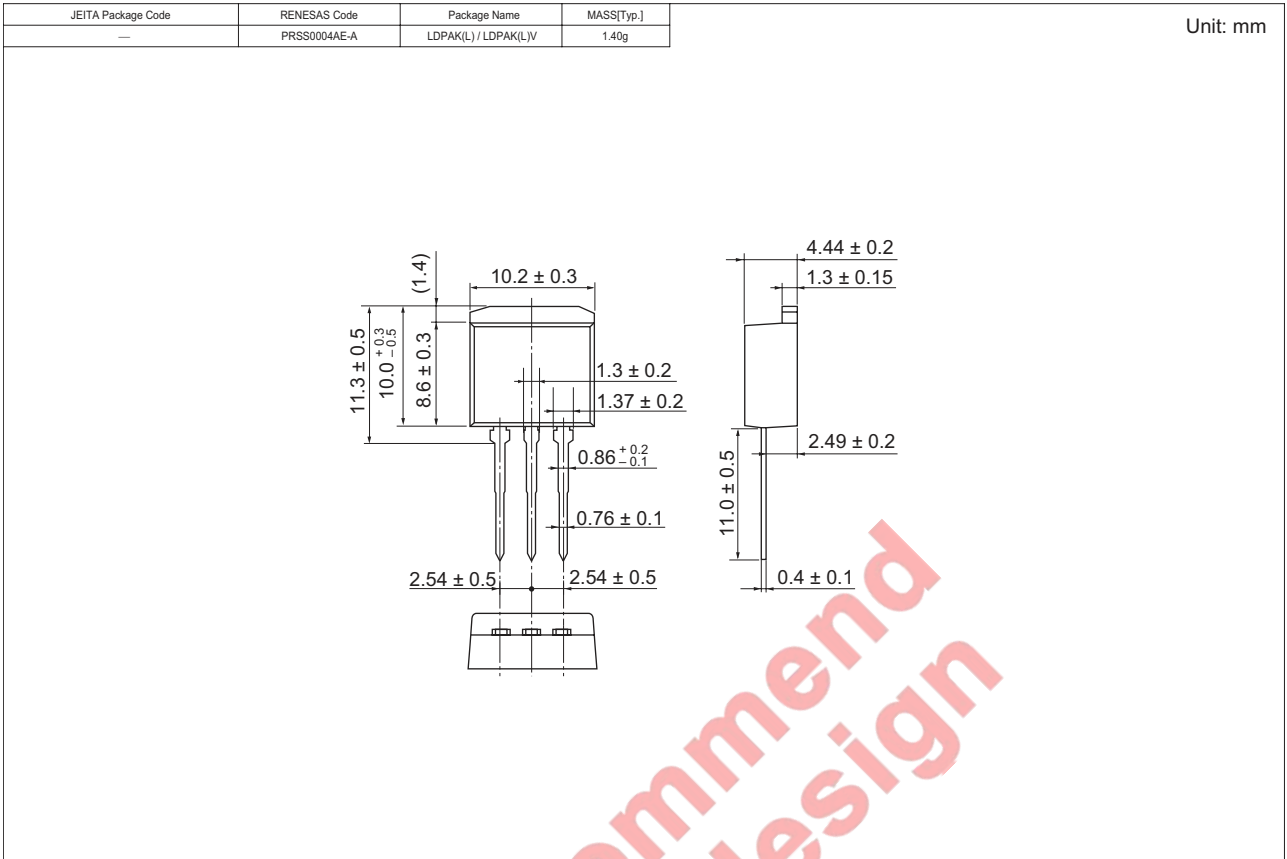


Waveform





Package Dimensions



### Ordering Information

Part Name	Quantity	Shipping Container
HAF1002-90L	Max: 50 pcs/sack	Sack
HAF1002-90S	Max: 50 pcs/sack	Sack
HAF1002-90STL	1000 pcs/Reel	Embossed tape
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